



TECHNISCHE UNIVERSITÄT DARMSTADT

Jonas Christ, Lorenzo Bortot, Jeroen van Nugteren, Laura D'Angelo, Arjan Verweij

# 1D Quench Propagation Analysis in HTS Tapes with the Spectral Element Method



# Outline

- Reminder: Numerical Aspects of SEM
- Background: HTS vs. LTS
- HTS-Applications in NIC
- Simulated Model
- Simulation Results
- Conclusion

No description of the underlying numerical method here – see presentation from 22/08/2019, https://indico.cern.ch/event/796548/contributions/3 532107/attachments/1895965/3128024/mid\_term \_presentation.pdf



# Numerical Aspects of SEM

- 1D Cheby-SEM and necessary framework has been implemented in Matlab
- Implementation has been verified for an academic example against FEM

Clear advantages of
 SEM compared to FEM
 for quench propagation
 have been shown:

See presentation from 22/08/2019

- 1. Simple refinement
  - Obtain desired accuracy
- 2. Less memory consumption
  - Cheaper application to larger geometries
- 3. Local resolution
  - Easy adaption to quench front



# Background: HTS vs. LTS





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# **HTS-Application in NIC**

- Non-insulated HTS coils
  - Wounded tapes with normal conducting filling/tape in between
  - Solenoid
  - Quench through impurities, ind. coupling, (massive) radiation ...





#### (Picture taken from tokamak energy, WAM-HTS presentation, 2019, https://indico.cern.ch/event/775529/contributions /3334053/attachments/1829923/3003215/20190 412 GB Stability and quench dynamic behav iour\_of\_Tokamak\_Energy\_REBCO\_QA\_coils\_In

dico.pdf)

#### Quench Propagation Analysis in HTS Tapes with the Spectral Element Method



# **HTS-Application in NIC**

- Non-insulated HTS coils
  - Current can bypass quenching region in adjacent turns
  - Turn-to-turn (T2T)
     resistance?
  - External protection?
  - Upscaling for larger magnets?



Understanding of single tape quench behavior required
➢ Normal zone development?
➢ Quench resistance?



# Model – Single HTS Tape

- Layers of Hastelloy, copper (x2), silver (x2) and Rebco
- External circuit:
  - Applied current *I*<sub>applied</sub> constant over time
  - No active protection schemes





# Model – Transient Simulation

- 1D Thermal runaway in HTS tape:
  - Ohmic losses
  - Thermal conduction
  - Adiabatic boundary
- Initial deposition of energy in tiny region around hotspot
- Simulate up to hotspot temperature of 300 K













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# Model – Visualisation









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# Model – Simulation Objectives





# Results I – Copper Layer Thickness

- Less Cu: less thermal transport
   = lower Vnzp
- More Cu: more total mass and less resistance

   less power in larger volume
  - = lower Vnzp





# **Results II – Cooling**

- Cooling in liquid He
   ~2 kW/m<sup>2</sup> K on total
   surface (non-practical)
- Rapid increase in reaction time, massive decrease in Vnzp
- Does not prevent burnout

   high cooling not a good
   idea?
- Low cooling
   -> insignificant influence





I. Cu layer II. Cooling III. V<sub>nzp</sub> IV. t<sub>react</sub> V. R<sub>quench</sub>

## Results III – Normal Zone Propagation Velocity

- For low temperatures

   (i.e. ~constant el.
   resistivity), Vnzp is
   found to be mainly a
   function of I
- More precisely:  $V_{nzp} \propto I^{x(B,T0)}$  with weak influence of T0





## **Results IV – Reaction Time**

- Time between 100 mV external voltage and 300 K at hotspot
- Above all, reaction time depends on applied current
- Precisely: power measure,  $t_{react} \propto I^{-2}$
- Is external reaction during a few <u>ms</u> feasible?





## Results V – Quench Resistance

- Exemplary: Resistance at end of simulation 300 K hotspot
- Clear dependency on applied current
- Significant influence of working point conditions
- Tuning of T2T
   resistance possible





# Summary

Single tape quench protection challenges:

- External:
  - Influence of applied current on reaction time ~ 1/l<sup>2</sup>
  - Very short reaction time
- In practical applications cooling without influence (if not even worsening the situation)

Construction of self protective NIC

- Tuning of T2T resistance
   requires knowledge of
   quench-resistance
- Self protection has to be very fast and effective
- Consideration of timeconstants?

How (if at all) is an active (external) protection scheme feasible?





# **Conclusion for Cheby-SEM**

### Matlab tool dedicated for

- Transient quench simulation
- Parameter studies
- Manual
- Documentation
- plug&play routines
- no need to understand the numerics

#### Beta-Version on Gitlab: https://gitlab.cern.ch/steam/steam-ChebySEM







## App 1.1 – Material Properties

- Influence of RRR and B relevant for low temperatures
- Less (parametrized) material data found for Ag, especially for high field or different RRR





## App 1.2 – Parameters on Critical Values





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# App 1.3 – (M)QE as Function of Working Point (Iapp,B,T0)

- Limits of calculation <u>here</u>: 50 – 1200 mJ, resolution 5 mJ (for runtime purposes)
- Minimum only for used initial temperature profile: Gaussian with fixed variance 3mm
  - ≻ (M)QE



QE of 5mJ in initial quench volume ~(12mm x 0.1mm x 10mm) > ~ 0.4 J/cm^3



## App 1.4 – Transient Behaviour

• (remember: default simulation settings)







# App 2.1 – Cu layer on Resistance

- Variation of layer thickness without significant influence for dCu > 10um
- constant factor  $\frac{V_{nzp} t_{react}}{d_{Cu}}$ (Wiedemann-Franz law?)





# App 2.2 – Including Ag Properties

- Same initial energy for same NC-thickness
- No significant influence
- Replacing with Cu for given simulation reasonable
- Influence of RRR of Cu and Ag may change this statement for low thicknesses





# App. - Reminder: Excerpt of Standar from 22/08/2019 Simulation Workflow





App. - Spectral Element Method (Section from 22/08/2019)

 Polynomial approximation of function

. .

$$f(\xi) \approx \sum_{n=0}^{N} \widetilde{f_n} \, \xi^n$$

• Chebyshev-polynomials  $T_n$ :  $T_0 = 1$ ,  $T_1 = \xi$ ,  $T_2 = 2 \xi^2 - 1$ , ...

> Orthogonality 
$$\bigvee$$
  
 $\int_{-1}^{1} T_n T_m \,\omega_T \,d\xi = c_n \delta_{n,m}$ 





App. - Spectral Element Method (Cheventation from 22/08/2019

function value

- Discretization of space with mesh and polynomials
- Discretized PDE as matrix equation for element wise representation

$$\theta^e \approx \sum_{n=0}^N u_n^e T_n$$

Sparse mesh, high order polynomials





# App. - Benchmark: Proof of Concept 22/08/2019

	Solver	Runtime	# DoF
Comsol	FEM, standard fine mesh	33 s	12.000
Comsol	FEM, adaptive mesh	15 s	400 - 500
Matlab	SEM, adaptive polynomial order	19 s	< 200

More general:

#### Pro FEM

- Multi-purpose tool
- Steep changes
- Inhomogeneous materials

#### Pro SEM:

- Specialized tool
- Accuracy
- Less storage requirements
- Simple refinement



Update on the application of spectral element methods on quench simulation

# App. - What's next? - Background in 22/08/2019

- Non-insulated (NI) HTS coils
  - Wounded tapes
  - Solenoid
  - Quench tolerant (Self protection)
- Planned application in fusion technology (cmp. e.g. tokamak energy)
- Application in accelerator technology?



(Picture taken from tokamak energy, WAM-HTS presentation, 2019,

https://indico.cern.ch/event/775529/contributions/3334053/attachm ents/1829923/3003215/20190412\_GB\_Stability\_and\_quench\_dyn amic\_behaviour\_of\_Tokamak\_Energy\_REBCO\_QA\_coils\_Indico.p df#search=van%20nugteren%20AND%20EventID%3A775529)



# App. - What's next? - Task

- Simulation of HTS tape peak temperature during quench
  - 1D simplified model
  - Current sharing btw. super- and normalconducting domains
  - Equivalent resistance
- Mid-term:
  - Coolant (1D + 1D)
  - Turn-to-turn propagation





